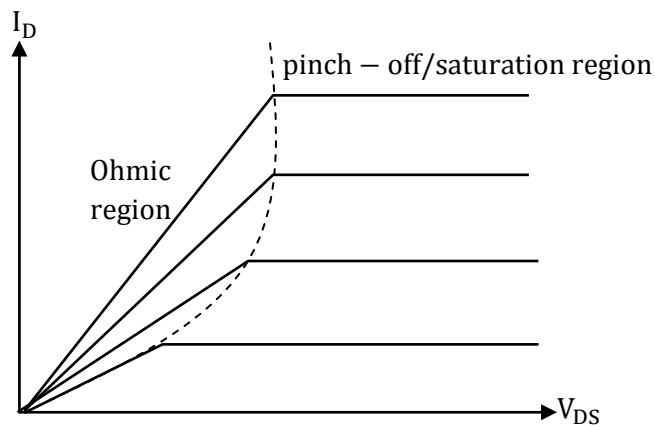


Electronic Device and Circuits

Answer Keys and Explanations

1. [Ans. C]

JFET can be used as voltage variable resistor (VVR) in linear (or) Ohmic region which is well below pinch-off.



∴ Option (C) is Correct.

2. [Ans. D]

MOS capacitor fabricated on a p-type Semiconductor is NMOS type V_{GS} applied should be positive which implies surface potential is positive and equal to Fermi potential.

3. [Ans. A]

$$\text{As } C_j \propto \frac{1}{\sqrt{V_R}}$$

$$C_j = K \cdot \frac{1}{\sqrt{V_R}}$$

$$C_j = 1 \text{ and } V_R = 1 \text{ then } K = 1$$

When

$$\text{For } V_R = 4 \text{ then } C_j = \frac{1}{\sqrt{4}} = 0.5 \text{ PF}$$

4. [Ans. *] Range: 1.03 to 1.04

$$\lambda = \frac{1.24}{E_g(\text{eV})} (\mu\text{m}) = \frac{1.21}{1.2} = 1.03 \mu\text{m}$$

5. [Ans. B]

6. [Ans. B]

$$\begin{aligned} \text{Minimum } V_{DS} \text{ for Saturation } V_{DS_{\min}} &= V_{GS} - V_P \\ &= -2 - (-4) = 2V \end{aligned}$$

∴ Option (B) is Correct.

7. [Ans.*] Range 40 to 40

$$\begin{aligned} C_{\text{Diffusion}} &= g\tau \\ &= \frac{I_D}{\eta V_T} = \tau \\ &= \frac{2 \times 10^{-3}}{2 \times 25 \times 10^{-3}} \times 1 \mu\text{sec} \\ &= 40 \text{ nF} \end{aligned}$$

8. [Ans. D]

$$\begin{aligned} p_o &= N_A = 1.25 \times 10^{15} \text{ cm}^{-3} \\ n_o &= 3 \times 10^{15} \text{ cm}^{-3}; n_i = 1.5 \times 10^{10} \text{ cm}^{-3} \\ V_S &= V_T \ln \left(\frac{N_A N_D}{n_i^2} \right) = 0.612 \text{ V} \end{aligned}$$

9. [Ans.*] Range 45 to 45

$$\begin{aligned} V_{D_S} &< V_{G_S} - V_{th}; \quad 0.1 < 0.2 \\ I_D &= \mu_n C_{ox} \left(\frac{W}{L} \right) \left[(V_{G_S} - V_{th}) (V_{D_S}) - \frac{V_{D_S}^2}{2} \right] \\ &= 0.003 \times \left[(0.2) (0.1) - \frac{(0.1)^2}{2} \right] = 45 \times 10^{-6} \end{aligned}$$

10. [Ans. A]

$$\text{Hole Diffusion current at distance of 'x' cm} = J_{P_0} \left(e^{\frac{V_D}{V_T}} - 1 \right) \cdot \exp \left(-\frac{x}{L_P} \right)$$

$$\text{Where } J_{P_0} = \frac{q D_P P_{n_0}}{L_P}$$

$$\text{and } L_P = \sqrt{D\tau} = 2.83 \times 10^{-4} \text{ cm}$$

$$P_{n_0} = \frac{n_i^2}{N_D} = 2.25 \times 10^4$$

$$\begin{aligned} J_{P_0} &= \frac{1.6 \times 10^{-9} \times 8 \times 2.25 \times 10^4}{2.83 \times 10^{-4}} \\ &= 1.017 \times 10^{-10} \text{ A/cm}^2 \end{aligned}$$

$$J_P \text{ at } x = 3 \mu\text{m} (= 3 \times 10^{-4} \text{ cm}) = 1.017 \times 10^{-10} (e^{0.61/0.0259} - 1) e^{-3/2.83}$$

$$J_P = 0.6 \text{ A/(cm}^2\text{)}$$

∴ Option (A) is Correct